20 V, 8.0 A, Low V_{CE(sat)} **NPN Transistor**

ON Semiconductor's e²PowerEdge family of low V_{CE(sat)} transistors are miniature surface mount devices featuring ultra low saturation voltage $(V_{\text{CE(sat)}})$ and high current gain capability. These are designed for use in low voltage, high speed switching applications where affordable efficient energy control is important.

Typical applications are DC-DC converters and power management in portable and battery powered products such as cellular and cordless phones, PDAs, computers, printers, digital cameras and MP3 players. Other applications are low voltage motor controls in mass storage products such as disc drives and tape drives. In the automotive industry they can be used in air bag deployment and in the instrument cluster. The high current gain allows e²PowerEdge devices to be driven directly from PMU's control outputs, and the Linear Gain (Beta) makes them ideal components in analog amplifiers.

• This is a Pb-Free Device

MAXIMUM RATINGS (T_A = 25°C)

| Rating | Symbol | Max | Unit |
|--------------------------------|------------------|----------------------------|------|
| Collector-Emitter Voltage | V _{CEO} | 20 | Vdc |
| Collector-Base Voltage | V _{CBO} | 20 | Vdc |
| Emitter-Base Voltage | V _{EBO} | 6.0 | Vdc |
| Collector Current - Continuous | I _C | 6.0 | Adc |
| Collector Current - Peak | I _{CM} | 8.0 | Α |
| Electrostatic Discharge | ESD | HBM Class 3B MM Class C | |

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|--|-----------------------------------|----------------|-------------|
| Total Device Dissipation, T _A = 25°C Derate above 25°C | P _D (Note 1) | 830 6.7 | mW mW/°C |
| Thermal Resistance, Junction-to-Ambient | R _{θJA} (Note 1) | 150 | °C/W |
| Total Device Dissipation, T _A = 25°C Derate above 25°C | P _D (Note 2) | 1.4 11.1 | W mW/°C |
| Thermal Resistance, Junction-to-Ambient | R _{θJA} (Note 2) | 90 | °C/W |
| Thermal Resistance, Junction-to-Lead #1 | R _{θJL} (Note 2) | 15 | °C/W |
| Junction and Storage Temperature Range | T _J , T _{stg} | -55 to +150 | °C |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

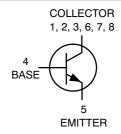
- FR-4 @ 100 mm², 1 oz copper traces.
 FR-4 @ 500 mm², 1 oz copper traces.



ON Semiconductor®

http://onsemi.com

20 VOLTS, 8.0 AMPS NPN LOW $V_{CE(sat)}$ TRANSISTOR EQUIVALENT $R_{DS(on)}$ 31 m Ω





ChipFET™ CASE 1206A STYLE 4

MARKING DIAGRAM

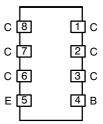


VD = Specific Device Code

M = Month Code

= Pb-Free Package

PIN CONNECTIONS



ORDERING INFORMATION

| Device | Package | Shipping [†] |
|----------------|----------------------|-----------------------|
| NSS20601CF8T1G | ChipFET (Pb-Free) | 3000/ Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

| Symbol | Min | Typical | Max | Unit |
|----------------------|--|---|--|---|
| l l | | | I | |
| V _{(BR)CEO} | 20 | - | - | Vdc |
| V _{(BR)CBO} | 20 | - | - | Vdc |
| V _{(BR)EBO} | 6.0 | - | - | Vdc |
| I _{CBO} | - | - | 0.1 | μAdc |
| I _{EBO} | - | - | 0.1 | μAdc |
| | | | | |
| h _{FE} | 200 200 200 200 200 200 | - - 365 - - | - - - - | |
| V _{CE(sat)} | - - - - - | 0.007 0.031 0.060 0.090 0.110 0.110 | 0.010 0.065 0.080 0.110 0.130 0.130 | V |
| V _{BE(sat)} | - | 0.760 | 0.900 | V |
| V _{BE(on)} | - | 0.720 | 0.900 | V |
| f _T | 140 | - | - | MHz |
| Cibo | - | - | 1100 | pF |
| Cobo | - | - | 100 | pF |
| | | | | |
| t _d | - | - | 110 | ns |
| t _r | - | - | 130 | ns |
| t _s | - | - | 850 | ns |
| t _f | - | - | 130 | ns |
| | V(BR)CEO V(BR)CBO V(BR)EBO ICBO IEBO VCE(sat) VBE(sat) VBE(on) fT Cibo Cobo td tr ts | V(BR)CEO 20 V(BR)CBO 20 V(BR)EBO 6.0 ICBO - IEBO - NFE 200 200 200 200 200 200 200 200 200 Tobo - The stantantantantantantantantantantantantant | V(BR)CEO 20 - V(BR)CBO 20 - V(BR)EBO 6.0 - ICBO - - IEBO - - VCE(sat) - 0.007 - 0.031 - - 0.090 - - 0.110 - VBE(sat) - 0.760 VBE(on) - 0.720 fT 140 - Cobo - - td - - ts - - | V(BR)CEO 20 - - V(BR)CBO 20 - - V(BR)EBO 6.0 - - ICBO - - 0.1 IEBO - - 0.1 hFE 200 - - 200 - - - 200 - - - 200 - - - 200 - - - 200 - - - 200 - - - 200 - - - 200 - - - 200 - - - 200 - - - 200 - - - 200 - - - 200 - - - 200 - - 0.010 0.060 0.080 0.110< |

^{3.} Pulsed Condition: Pulse Width = 300 $\mu sec,$ Duty Cycle \leq 2%.

TYPICAL CHARACTERISTICS

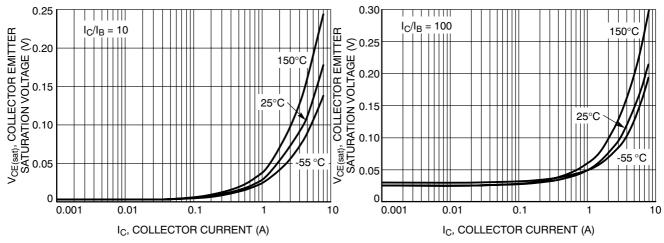


Figure 1. Collector Emitter Saturation Voltage vs. Collector Current

Figure 2. Collector Emitter Saturation Voltage vs. Collector Current

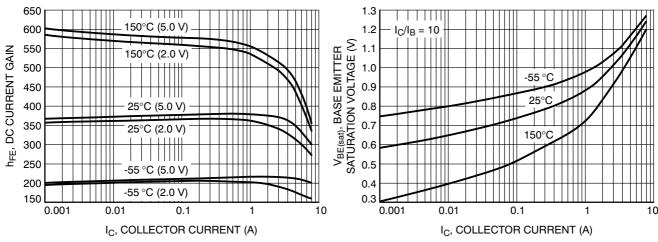


Figure 3. DC Current Gain vs. Collector Current

Figure 4. Base Emitter Saturation Voltage vs.
Collector Current

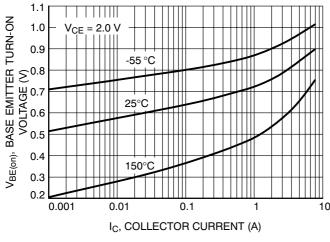


Figure 5. Base Emitter Turn-On Voltage vs.
Collector Current

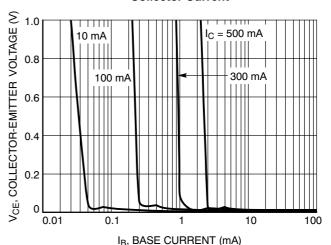


Figure 6. Saturation Region

TYPICAL CHARACTERISTICS

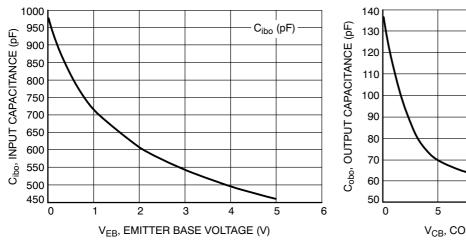


Figure 7. Input Capacitance

Figure 8. Output Capacitance

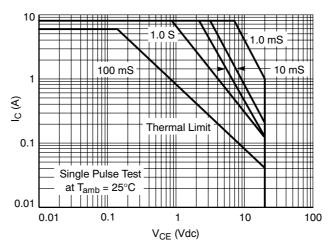
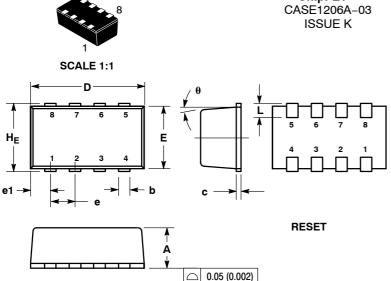


Figure 9. Safe Operating Area



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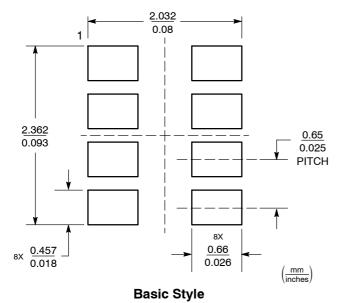
NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: MILLIMETER.
- MOLD GATE BURRS SHALL NOT EXCEED 0.13 MM PER SIDE.
- LEADFRAME TO MOLDED BODY OFFSET IN HORIZONTAL AND VERTICAL SHALL NOT EXCEED 0.08 MM. DIMENSIONS A AND B EXCLUSIVE OF MOLD GATE BURRS. 5
- NO MOLD FLASH ALLOWED ON THE TOP AND BOTTOM LEAD

| | MILLIMETERS | | | | INCHES | |
|-----|-------------|------|------|-----------|-----------|-------|
| DIM | MIN | NOM | MAX | MIN | NOM | MAX |
| Α | 1.00 | 1.05 | 1.10 | 0.039 | 0.041 | 0.043 |
| b | 0.25 | 0.30 | 0.35 | 0.010 | 0.012 | 0.014 |
| C | 0.10 | 0.15 | 0.20 | 0.004 | 0.006 | 0.008 |
| D | 2.95 | 3.05 | 3.10 | 0.116 | 0.120 | 0.122 |
| E | 1.55 | 1.65 | 1.70 | 0.061 | 0.065 | 0.067 |
| е | 0.65 BSC | | | | 0.025 BSC |) |
| e1 | 0.55 BSC | | | 0.022 BSC | | |
| L | 0.28 | 0.35 | 0.42 | 0.011 | 0.014 | 0.017 |
| HE | 1.80 | 1.90 | 2.00 | 0.071 | 0.075 | 0.079 |
| θ | 5° NOM | | | | 5° NOM | |

| STYLE 1: | STYLE 2: | STYLE 3: | STYLE 4: | STYLE 5: | STYLE 6: |
|--------------------------|----------------------------|---------------------------|-----------------------------|---------------------------|--------------------|
| PIN 1. DRAIN | PIN 1. SOURCE 1 | PIN 1. ANODE | PIN 1. COLLECTOR | PIN 1. ANODE | PIN 1. ANODE |
| 2. DRAIN | 2. GATE 1 | 2. ANODE | 2. COLLECTOR | ANODE | 2. DRAIN |
| DRAIN | SOURCE 2 | SOURCE | COLLECTOR | DRAIN | 3. DRAIN |
| 4. GATE | 4. GATE 2 | 4. GATE | 4. BASE | DRAIN | 4. GATE |
| SOURCE | 5. DRAIN 2 | 5. DRAIN | EMITTER | SOURCE | 5. SOURCE |
| DRAIN | 6. DRAIN 2 | 6. DRAIN | COLLECTOR | GATE | 6. DRAIN |
| 7. DRAIN | 7. DRAIN 1 | CATHODE | COLLECTOR | CATHODE | 7. DRAIN |
| 8. DRAIN | 8. DRAIN 1 | CATHODE | COLLECTOR | CATHODE | 8. CATHODE / DRAIN |
| | | | | | |

SOLDERING FOOTPRINT



GENERIC MARKING DIAGRAM*



= Specific Device Code XXX

= Month Code Μ

= Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " •", may or may not be present.

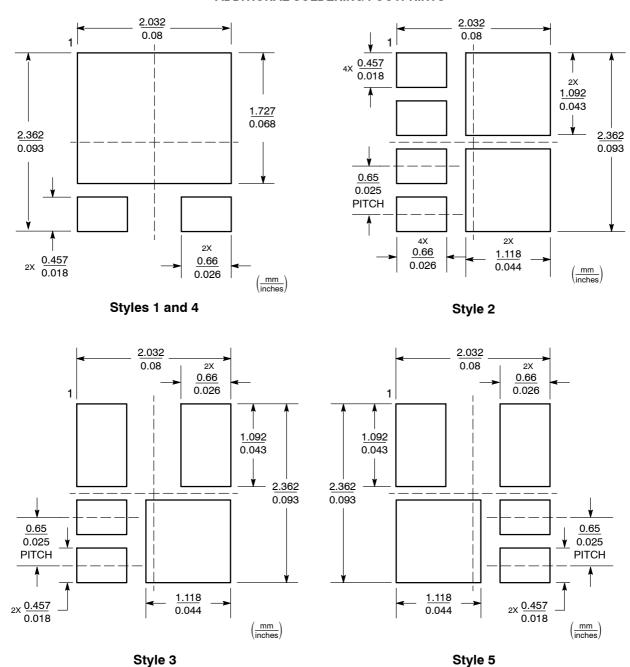
OPTIONAL SOLDERING FOOTPRINTS ON PAGE 2

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ADDITIONAL SOLDERING FOOTPRINTS*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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